

## Description

The SiT5711 is the industry's smallest (9 mm x 7 mm) package, stratum 3E compliant oscillator with  $\pm 5$  ppb over-temp stability and  $\pm 0.8$  ppb per day short term aging.

By combining SiTime's unique DualMEMS™ temperature sensing and TurboCompensation™ technology, the SiT5711 delivers stable timing in the presence of environmental hazards – air flow, temperature perturbation, vibration, shock and electromagnetic interference (EMI). This environmental robustness enables placement of the device anywhere on the PCB without any cover or mechanical shielding.

The SiT5711 can be factory-programmed to any frequency between 1 and 60 MHz. This programmability enables designers to optimize clock configuration while eliminating the long lead time and customization cost associated with quartz based OCXOs of which each frequency is custom built.

### **Features**

- Any frequency between 1 and 60 MHz, in 1Hz steps
- ±0.3 ppb/°C frequency slope (ΔF/ΔT)
- ±5 ppb over-temperature stabilities.
   Contact SiTime for ±2 and ±3 ppb options
- Up to 85°C operating temperature ranges, contact SiTime for 105°C option
- 3e-11 ADEV at 1 second average time
- Exceptional dynamic stability under airflow and rapid temperature changes
- Excellent Holdover over a wide range of conditions
- Integrated regulators for on-chip power-supply noise filtering and excellent PSRR
- GR-1244 Stratum 3E compliant
- Resistant to shock, vibration and board bending
- 3.3V supply voltage (contact SiTime for other voltages)
- Contact SiTime for I<sup>2</sup>C Voltage Control options
- LVCMOS output, Contact SiTime for Clipped Sinewave
- RoHS and REACH compliant, Pb-free, Halogen-free and Antimony-free

## **Applications**

- v∎// 4G/5G radio /⁄
- Base Stations
- Digital Switching
- Time and Frequency Measurement
- IEEE1588
- Test and measurement

## 9.0 x 7.0 mm Package

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Figure 1. Top and bottom view

## **Package Pinout**

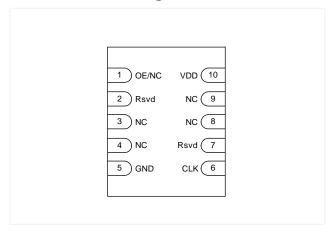


Figure 2. Pin Assignments (Top view)



## **Electrical Characteristics**

All Min and Max limits are specified over temperature and rated operating voltage with 15 pF output load unless otherwise stated. Typical values are at 25°C and 3.3V VDD.

**Table 1. Output Characteristics** 

Parameters	Symbol	Min.	Тур.	Max.	Unit	Condition	
	Frequency Coverage						
Output Frequency Range	F	1	-	60	MHz		
Frequency Stability							
Frequency Stability over Temperature	F_stab	-5	-	+5	ppb	Referenced to (fmax + fmin)/2 over the specified	
		-8	-	+8	ppb	temperature range	
Frequency vs. Temperature Slope	ΔΕ/ΔΤ	-	±0.3	-	ppb/°C	In still air, 1°C/min ramp rate	
Dynamic Frequency Change to Temperature Ramp	F_dynamic	-	±0.005	-	ppb/s	In still air, 1°C/min ramp rate	
Initial Tolerance	F_init	-	±500	-	ppb	Initial frequency at 25°C inclusive of solder-down shift at 48 hours after 2 reflows	
24-hour drift	F_24_Drift	_	±0.9	-	ppb	Measured at 25°C after 30 days continuous operation	
Hysteresis Over Temperature	F_Hys	-	-	+1	ppb	Over -20 to 70 °C, measured as max frequency spread of hysteresis eye	
		-	-	+1.6	ppb	Over -40 to 85 °C, measured as max frequency spread of hysteresis eye	
One-Day Aging	F_1d	-	±0.8	-	ppb	After 30-days operation	
One-Month Aging	F_1m	-	±25	-	ppb	After 30-days operation	
One-Year Aging	F_1y	-	±150	-	ppb	After 30-days operation	
20-Year Aging	F_20y	ı	±500	-	ppb	After 30-days operation	
Total Stability – 20 years	F_20y_stab	-4.6	_	+4.6	ppm	Stratum 3E per GR-1244 Core. Inclusive of initial tolerance, frequency stability over temperature, 20-year aging, and variations to supply voltage and output load. Typically called free running accuracy	
Supply Voltage Sensitivity	F_vdd	7	±1,0	-7	7/ppb	Vdd ±5%)	
Output Load Sensitivity	)F_load //	MEP.	////±1///		// ppb/	LVCMOS output, 15 pF ±10%	
		-	±1	<u> </u>	ppb	Clipped sinewave output, 10kΩ, 10 pF ±10%	
		S	tart-up Cha	racteristics	S		
Start-up Time	T_start	-	5	_	ms	Time to first pulse	
Time to Rated Stability	T_stability	-	2	_	min	Time to first accurate pulse within rated stability	
		LVCI	MOS Outpu	t Characte	ristics		
Duty Cycle	DC	45	-	55	%		
Rise/Fall Time	tr, tf		1		ns	10% - 90% VDD	
Output Voltage High	$V_{OH}$	90%			$V_{DD}$	$I_{OH} = -6 \text{ mA}, \text{ (Vdd} = 3.3 \text{V)}$	
Output Voltage Low	V <sub>OL</sub>			10%	$V_{DD}$	$I_{OL} = 6 \text{ mA}, (Vdd = 3.3V)$	
		Clipped S	Sinewave O	utput Char	acteristics		
Output Voltage Level	V <sub>OUT</sub>	0.8	_	1.2	V	Measured peak-to-peak swing at any Vdd – $10k\Omega \parallel 10$ pF ±10%	
Rise/Fall Time	tr, tf		1		ns	10% - 90% V <sub>DD</sub>	

**Table 2. DC Characteristics** 

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Parameters	Symbol	Min.	Тур.	Max.	Unit	Condition
			Supply	Voltage		
Supply Voltage	$V_{DD}$	3.14	3.3	3.47	V	Contact SiTime for other voltage options
	Power Consumption					
Power Consumption – Warm up	Pwr_warmup		2.5		W	Max power may be configurable lower, higher max gives shorter time.
Power Consumption – Steady State	Pwr_steady		0.60		W	At +50°C
Temperature Range						
Operating Temperature Range	T_use	-20	_	+70	°C	Extended commercial
		-40	-	+85	°C	Industrial. Contact SiTime for 105°C support



## **Table 3. Input Characteristics**

Parameters	Symbol	Min.	Тур.	Max.	Unit	Condition
Input Characteristics – OE Pin						
Input Impedance	Z_in	-	30	-	kΩ	Internal pull up to VDD
Input High Voltage	VIH	70	-	-	%	
Input Low Voltage	VIL	-	-	30	%	

### Table 4. Jitter & Phase Noise

Parameters	Symbol	Min.	Тур.	Max.	Unit	Condition	
Jitter							
RMS Period Jitter	T_jitt	-	0.8	-	ps	F = 10 MHz, population 10k	
RMS Phase Jitter (random)	T_phj	-	0.31	-	ps	F = 10 MHz, Integration bandwidth = 12 kHz to 5 MHz	
		-	0.31	-	ps	F = 50 MHz, Integration bandwidth = 12 kHz to 20 MHz	
Peak Cycle-to-Cycle Jitter	T_jitt_cc	_	6	-	ps	F = 10 MHz, population 1k, measured as absolute value	
			Allan D	eviation			
au = 1 second	AD_1s	-	3 E-11	-			
$ au = 10 \ seconds$	AD_10s	-	2 E-11	-			
$ au = 100 \ seconds$	AD_100s	-	2 E-11	-			
			Phase	Noise			
1 Hz offset		-	-80	-	dBc/Hz		
10 Hz offset		_	-108	-	dBc/Hz		
100 Hz offset		_	-127	-	dBc/Hz		
1 kHz offset		_	-148	-	dBc/Hz	Reference f = 10 MHz	
10 kHz offset		_	-154	-	dBc/Hz		
100 kHz offset		-	-154	_	dBc/Hz		
1 MHz offset		-	-167	7	dBc/Hz		
5 MHz offset		-	-168	A-	dBc/Hz		

## Table 5. Absolute Maximum Limits

Attempted operation outside the absolute maximum ratings may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	°C
Vdd	-0.5	4	V
Electrostatic Discharge	-	2000	V
Soldering Temperature (follow standard Pb-free soldering guidelines)	_	260	°C

## Table 6. Environmental Compliance

Parameter	Condition/Test Method
Mechanical Shock	MIL-STD-883F, Method2002
Mechanical Vibration	MIL-STD-883F, Method2007
Temperature Cycle	JESD22, MethodA104
Solderability	MIL-STD-883F, Method2003
Moisture Sensitivity Level	TBD



## **Pin-outs**

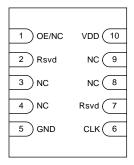


Figure 3. Pin Assignments (Top view)

## **Table 7. Pin Description**

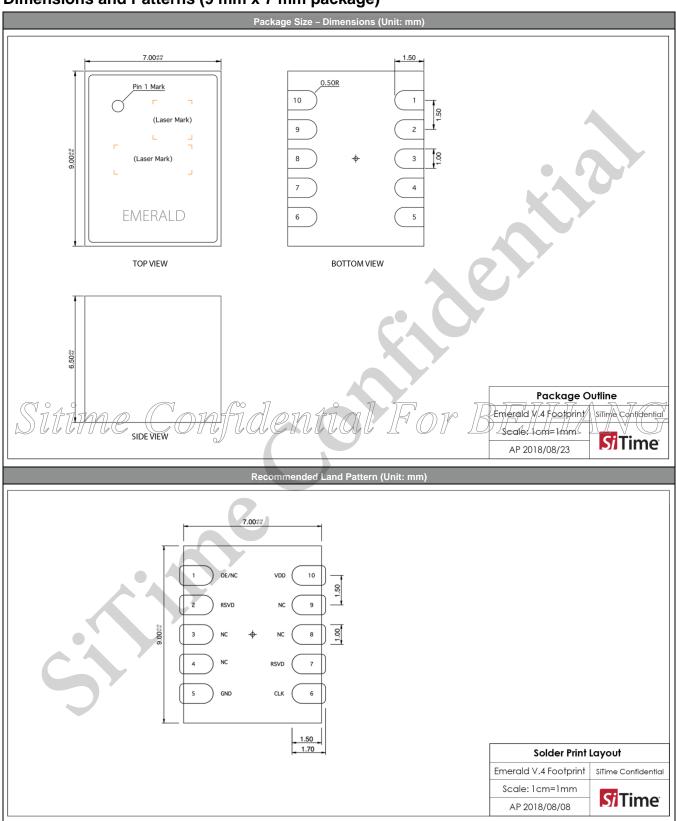
Pin	Symbol	I/O	Internal Pull-up/Pull Down Resistor	Function			
1	OE/NC	OE – Input	100 kΩ Pull-Up	H <sup>[1]</sup> : specified frequency output L: output is high impedance. Only output driver is disabled			
		NC - No Connect	-	H or L or Open: No effect on output frequency or other device functions			
2	Rsvd	Reserved	-	Connect to VDD or leave it open			
3	NC	No Connect	-	H or L or Open: No effect on output frequency or other device functions			
4	NC	No Connect	-	H or L or Open: No effect on output frequency or other device functions			
5	GND	Power	-	Connect to ground <sup>[2]</sup>			
6	CLK	Output	-	LVCMOS, or clipped sinewave oscillator output			
7	1 Rsvd	Reserved	1 d 0 70 1 7	Connect to VDD or leave it open			
(8)	66 MC/1/6	No Connect	JUUEIUU	Hor L or Open No effect on output frequency or other device functions			
9	NC	No Connect		H or L or Open: No effect on output frequency or other device functions			
10	VDD	Power	-	Connect to VDD			

### Notes:

- 1. In OE mode, a pull-up resistor of 100 k $\Omega$  or less is recommended if pin 1 is not externally driven. If pin 1 needs to be left floating, use the NC option.
- 2.  $0.1\,\mu\text{F}$  capacitor in parallel with a 10  $\mu\text{F}$  capacitor are required between VDD and GND.



## Dimensions and Patterns (9 mm x 7 mm package)





## **Layout Guidelines**

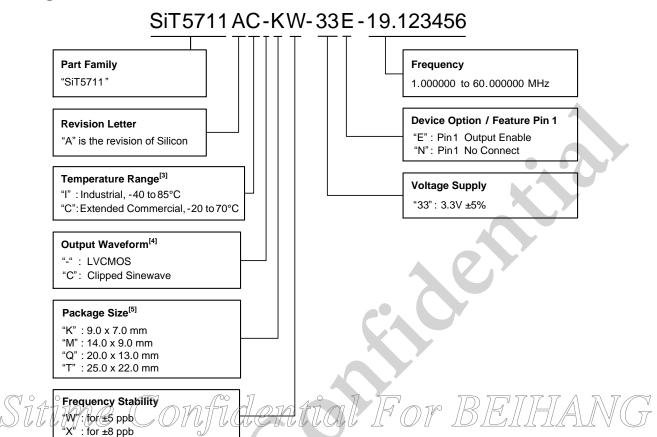
- SiT5711 uses internal regulators to minimize the impact of the power supply noise. For further reduction of noise, it is essential to use two bypass capacitors (0.1 µF and 10 µF). Place the bypass capacitors as close to the VDD as possible, typically within 1 to 2 mm. Ensure 0.1uF cap the closest to the device VDD and GND power pins.
- It is also recommended to connect all NC pins to the ground plan and place multiple vias under GND pin for maximum heat dissipation.
- For additional layout recommendations, refer to the Best Design Layout Practices.

## **Manufacturing Guidelines**

- No Ultrasonic or Megasonic Cleaning: Do not subject the SiT5711 to an ultrasonic or megasonic cleaning environment. Permanent damage or long-term reliability issues to the device may occur in such an
- No metal cover. Unlike legacy quartz OCXO, SiT5711 is engineered to operate reliably without performance degradation, in the presence of ambient disturbers such as airflow and sudden temperature changes. Therefore, the use of a metal cover typical of quartz OCXO is not needed.
- Reflow profile, per JESD22-A113D.
- For additional manufacturing guidelines and marking/ tape-reel instructions, refer to SiTime Manufacturing Notes.



## **Ordering Information**



#### Notes:

- 3. Contact SiTime for higher temperature range options
- 4. "-" corresponds to the default rise/fall time for LVCMOS output as specified in Table 1 (Electrical Characteristics). Contact SiTime for other rise/fall time options for best EMI.
- 5. Contact SiTime for 14.0 x 9.0 mm, 20.0 x 13.0 mm, 25.0 x 22.0 mm footprints.



#### **Table 8. Evaluation tools**

Ordering Code	Description	Document
SiT6730	Evaluation board for the Emerald family of holdover oscillators	Contact SiTime

### **Table 9. Additional Information**

Document	Description	Download Link
SiT6730 EVB	Evaluation board, contact SiTime	_
Time Machine II	MEMS oscillator programmer	http://www.sitime.com/support/time-machine-oscillator-programmer
Field Programmable Oscillators	Devices that can be programmable in the field by Time Machine II	http://www.sitime.com/products/field-programmable-oscillators
Manufacturing Notes	Tape & Reel dimension, reflow profile and other manufacturing related info	http://www.sitime.com/manufacturing-notes
Qualification Reports	RoHS report, reliability reports, composition reports	http://www.sitime.com/support/quality-and-reliability
Performance Reports	Additional performance data such as phase noise, current consumption and jitter for selected frequencies	http://www.sitime.com/support/performance-measurement-report
Termination Techniques	Termination design recommendations	http://www.sitime.com/support/application-notes
Layout Techniques	Layout recommendations	http://www.sitime.com/support/application-notes

### Table 10. Revision History

Version	Release Date	Change Summary
0.1	07/17/2018	First release, advanced information
0.11	07/27/2018	Changed Pin 2 and Pin 7 to Rsvd
0.12	08/08/2018	Added 9x7 mm package option in the ordering code Added 9x7 mm package pad layout recommendation Misc. corrections
0.13	08/09/2018	Removed 10 mm x 10 mm package  Misc. formatting-changes
0.14 [1	08/27/2018	Added #3 ppb support Added 14.0 x 9.0 mm, 20.0 x 13.0 mm, 25.0 x 22.0 mm packages Updated Table 1 and Ordering information Added Package Drawing section

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